

ABSTRACT OF THE DISCLOSURE

A single crystal pulling apparatus for a metal fluoride comprising a crucible provided in a chamber and

5 filling a molten solution of a single crystal manufacturing material, a melting heater provided to surround the crucible, a vertically movable single crystal pulling bar including a seed crystal on a tip and coming in contact with the molten solution of the single crystal

10 manufacturing material filled in the crucible, a heat insulating wall provided in the chamber to surround at least a peripheral side portion of a single crystal pulling region in an upper part of the crucible, a ceiling board for closing an opening portion of an upper end in an upper

15 part of the heat insulating wall, and a single crystal pulling chamber surrounded by the heat insulating wall and the ceiling board, wherein the ceiling board is provided with at least an inserting hole for inserting the single crystal pulling bar, and a coefficient of thermal

20 conductivity in a direction of a thickness of the ceiling board is 1000 to 50000 W/m²·K.